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Effects of Zeeman spin splitting on the modular symmetry in the quantum Hall effect

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Abstract

Magnetic-field-induced phase transitions in the integer quantum Hall effect are studied under the formation of paired Landau bands arising from Zeeman spin splitting. By investigating features of modular symmetry, we showed that modifications to the particle-hole transformation should be considered under the coupling between the paired Landau bands. Our study indicates that such a transformation should be modified either when the Zeeman gap is much smaller than the cyclotron gap, or when these two gaps are comparable. © 2005 Elsevier Ltd. All rights reserved.

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Two types of magnetic-field-induced phase transitions, plateau–plateau and insulator-quantum Hall (I-QH) transitions, can be observed in the quantum Hall effect (QHE) as we applied a magnetic field B perpendicular to a two-dimensional (2D) system [1–3]. Based on the law of corresponding states [1], universal features of the $\Gamma_0(2)$ modular symmetry such as the semicircle law and universal critical conductivities can be found in all magnetic-field-induced phase transitions [2]. In such a law, however, effects due to the Zeeman spin splitting are ignored. Dolan [2] suggested that the spin splitting can reduce the modular symmetry from $\Gamma_0(2)$ to $\Gamma(2)$, under which the universality of the critical conductivities can become invalid while the trace $\sigma_{xx}(\sigma_{xy})$ follows

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the semicircle law. Here σ_{xx} and σ_{xy} are the longitudinal and Hall conductivities. The deviation of the critical point can be explained by the generalization of the particle-hole transformation under $\Gamma(2)$ symmetry [2]. In most 2D systems, as shown in the inset (a) of Fig. 1, the cyclotron splitting is much larger than the spin splitting. The two Landau bands separated by the spin gap are paired, and the coupling between the paired bands can reduce the modular symmetry to $\Gamma(2)$. In addition, recent studies suggest that the (generalized) particle-hole transformation may need to be modified as well when the gap inducing QH state is small [4]. Since such a transformation is important to the semicircle law [2,5], the deviation of such a law is also expected under a small spin gap.

In this paper, we investigate three different 2D systems to study the effects of Zeeman spin splitting in the integer quantum Hall effect (IQHE). We benefit from the fact that these samples have been examined in Refs. [3,6,7]. Table 1 summarizes the systems under study and the corresponding transitions. For convenience, we denote a QH state by its filling factor ν and the insulating state by the number '0'.

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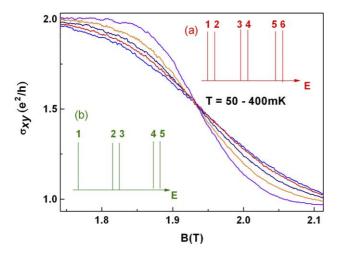


Fig. 1. The Hall conductivity in the 2–1 transition in sample A. The inset (a) and (b) show the spin configurations for sample A (and B) and C.

In addition, a magnetic-field-induced transition is characterized by its adjacent two states [1–3].

In Fig. 2, the solid line and dash dot line are the traces of $\sigma_{xx}(\sigma_{xy})$ in the 2–0 and 2–1 transitions of sample B at the gate voltage $V_g = -0.26 \,\mathrm{V}$ when the temperature T =50 mK. At low B, the sample is a spin-degenerate system which behaves as an insulator, and undergoes a 2-0 transition to enter QH liquid with increasing B. In such a transition, $\sigma_{xx}(\sigma_{xy})$ is along the expected semicircle, the dashed line, when $\sigma_{xy} > e^2/h$ because of the validity of the semicircle law at the side of QH liquid [8]. With increasing B, the spin splitting becomes resolved we can observe the 2–1 and 1–0 transitions. The trace $\sigma_{xx}(\sigma_{xy})$ is not along the semicircle in the 2–1 transition although at lower B such a law is observed at the QH side in the 2–0 (spin-degenerate) transition, which indicates that the semicircle law is not strictly followed as the spin splitting is just resolved. On the other hand, as shown in Fig. 1, a well-defined T-independent point can be identified in σ_{xy} in the 2–1 transition. Such a point is the critical point, and we can see that the critical Hall conductivity is close to the universal value 1.5 e^2/h . Therefore, the universality of critical Hall conductivity can survive under the invalidity of the semicircle law when the spin splitting is just resolved. In fact, it is expected that universalities are very robust in σ_{xy} since σ_{xy} is an important quantity to construct the phase diagram of QHE [4,9]. However, it is also shown by our group [3] that the semicircle law holds well in sample A with the invalidity of universal critical conductivities when the spin splitting is

Table 1
The systems and transitions under study

Sample	System	Transitions
A [3]	2D GaAs electron system	2-1, 1-0
B [6]	2D GaAs electron system with InAs dots	2-0, 2-1, 1-0
C [7]	2D SiGe hole system	3-2, 2-1

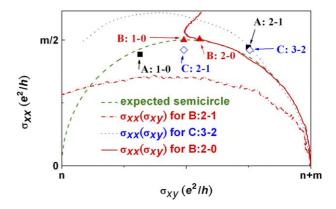


Fig. 2. The trace of $\sigma_{xx}(\sigma_{xy})$ and critical point. Here n=0, 0, 1, and 2 for the 1–0, 2–0, 2–1, and 3–2 transitions, respectively. In addition, m=2 for the 2–0 transition and m=1 for all the other transitions. Each symbol corresponds to a critical point.

resolved but is still small. In Fig. 2, the critical points of the 2–1 and 1–0 transitions of sample A deviate from the top position of the semicircle, which indicates the invalidity of universal critical conductivities [2]. The deviation in the 2–1 transition indicates $\Gamma(2)$ symmetry [2].

To further study the effects due to Zeeman spin splitting, we investigate the transitions in sample C. The sample is of a p-type Si/SiGe heterostructure, where the spin splitting is comparable to the cyclotron energy [7]. As shown in the inset (b) of Fig. 1, the Landau bands also appear in pairs except the lowest Landau band in such heterostructures. When the paired Landau bands are unresolved, only QH states of odd filling factors can be observed. In sample C, the $\nu = 2$ state is the first well-resolved QH state of the even filling factor, and thus the 3-2 and 2-1 transitions are suitable to study the effects due to paired Landau bands. In Fig. 2, the dotted line is the trace $\sigma_{xx}(\sigma_{xy})$ in the 3-2 transition at T=70 mK, and the open diamond (C: 3–2) denotes the corresponding critical point located at $(2.76 e^2/h, 0.46 e^2/h)$. The critical point is close to the expected semicircle although it is not at the top of the semicircle. In addition, the trace $\sigma_{xx}(\sigma_{xy})$ is also close to the expected semicircle on the right-hand side of the critical point, so features of $\Gamma(2)$ symmetry are observed. On the other hand, $\sigma_{xx}(\sigma_{xy})$ deviates from the semicircle on the left-hand side of the critical point at the same temperature. Therefore, the modular symmetry can be reduced to $\Gamma(2)$, and the exactness of the semicircle law can be relaxed under the paired Landau bands. As mentioned above, the deviations of the critical conductivities may be due to the generalization of particle-hole transformation, and the deviation of the semicircle law is expected when such a transformation has to be modified under a small spin gap. Since we observed these effects in both the p-type Si/SiGe and n-type GaAs systems, modifications to the particle-hole transformation are important either when the spin splitting is much smaller than the cyclotron gap, or when these two gaps are comparable.

In sample C, the semicircle law holds well and the critical point is at the top of the semicircle in the 2-1 transition. Comparing with the 3–2 transition in the same sample, the 2-1 transition occurs at higher B where the gaps inducing QH states are larger. Therefore, the larger the gaps, the better the semicircle law and the universality of the critical conductivities. It can be seen in Fig. 2 that the critical points in the 2-0 and 1-0 I-QH transitions are both at the top of the semicircle in sample B, and the semicircle law is not followed well in the 2–1 transition. In sample A, however, there is a deviation on the critical point in the 1-0 I-QH transition. We note that such deviation in an I-QH transition may also be due to the conversion from resistivities inappropriate conductivities [2].

In conclusion, we studied effects of Zeeman splitting in the IQHE. Under the paired Landau bands arising from Zeeman spin splitting, the exactness of semicircle law can be relaxed, and the modular symmetry can be reduced to $\Gamma(2)$. Our study indicates the importance of the modifications to the particle-hole transformation either when the spin gap is much smaller than the cyclotron gap, or when these two gaps are comparable.

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